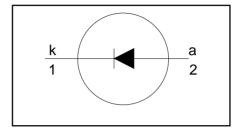
# **PBYR1645F**, **PBYR1645X**

## **FEATURES**

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Isolated mounting tab

## **SYMBOL**



## QUICK REFERENCE DATA

$$V_R = 40 \text{ V} / 45 \text{ V}$$
 $I_{F(AV)} = 16 \text{ A}$ 
 $V_F \le 0.6 \text{ V}$ 

#### **GENERAL DESCRIPTION**

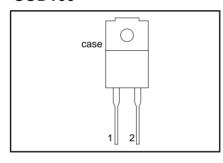
Schottky rectifier diodes in a plastic envelope with electrically isolated mounting tab. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR1645F is supplied in the SOD100 package. The PBYR1645X is supplied in the SOD113 package.

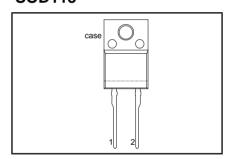
## **PINNING**

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	isolated		

#### **SOD100**



## **SOD113**



# **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	RAMETER CONDITIONS		MA	AX.	UNIT
V	Dook ropotitivo rovorgo	PBYR16 PBYR16		40F 40X	45F 45X	V
$V_{RRM}$	Peak repetitive reverse voltage		-	40	45	V
$V_{RWM}$	Working peak reverse voltage		-	40	45	V
$V_R$	Continuous reverse voltage	T <sub>hs</sub> ≤ 97 °C	-	40	45	V
I <sub>F(AV)</sub>	Average rectified forward current	square wave; $\delta$ = 0.5; $T_{hs} \le 95$ °C	-	1	6	Α
I <sub>FRM</sub>	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{hs} \le 95$ °C	-	3	2	А
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10  ms t = 8.3  ms sinusoidal; $T_j = 125 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{\text{RRM(max)}}$	-		20 32	A A
I <sub>RRM</sub>	Peak repetitive reverse surge current	pulse width and repetition rate limited by T <sub>i max</sub>	-	•	1	Α
T <sub>j</sub>	Operating junction temperature	, max	-	15	50	°C
$T_{stg}$	Storage temperature		- 65	17	75	°C

PBYR1645F, PBYR1645X

# **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs}$  = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	Peak isolation voltage from both terminals to external heatsink	SOD100 package; R.H. ≤ 65%; clean and dustfree	ı	1	1500	<b>V</b>
V <sub>isol</sub>	R.M.S. isolation voltage from both terminals to external heatsink	SOD113 package; f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-	-	2500	V
C <sub>isol</sub>	Capacitance from pin 1 to external heatsink	f = 1 MHz	-	10	-	pF

# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub>	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.2	K/W
R <sub>th i-a</sub>	1	in free air	-	55	-	K/W

# **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	$I_F = 16 \text{ A}; T_i = 125^{\circ}\text{C}$	-	0.53	0.6	٧
		$I_{\rm F} = 16  {\rm A}$	-	0.55	0.68	V
I <sub>R</sub>	Reverse current	$\dot{V}_R = V_{RWM}$	-	0.2	1.7	mΑ
		$V_R = V_{RWM}$ ; $T_j = 100^{\circ}C$	-	27	40	mΑ
$C_d$	Junction capacitance	$V_R = 5 \hat{V}$ ; $f = 1 MHz$ , $T_j = 25 \hat{C}$ to 125 $\hat{C}$	-	470	-	pF

# PBYR1645F, PBYR1645X

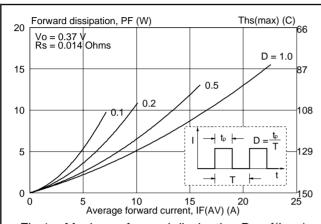


Fig.1. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

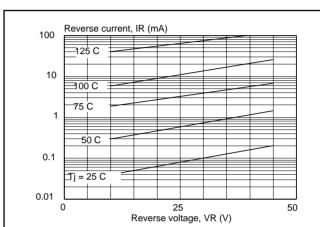


Fig.4. Typical reverse leakage current;  $I_R = f(V_R)$ ; parameter T<sub>i</sub>

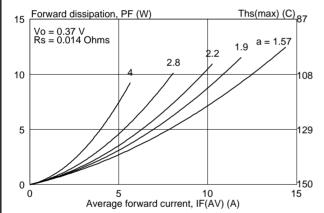
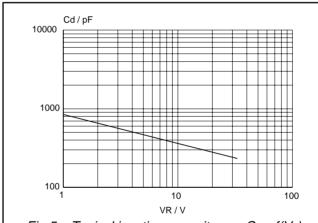


Fig.2. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = f(AV) $factor = I_{F(RMS)} / I_{F(AV)}$ .



Typical junction capacitance;  $C_d = f(V_R)$ ; f = 1 MHz;  $T_j = 25^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ .

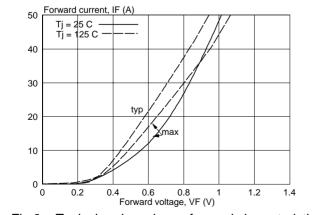
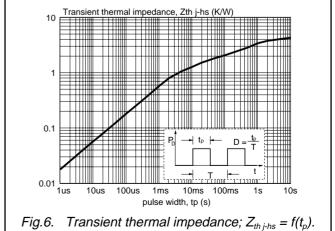
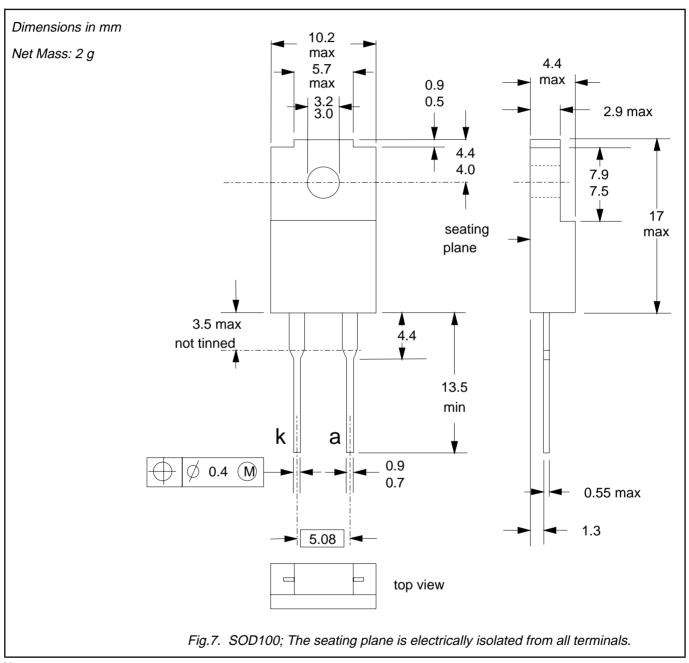


Fig.3. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_i$ 



PBYR1645F, PBYR1645X

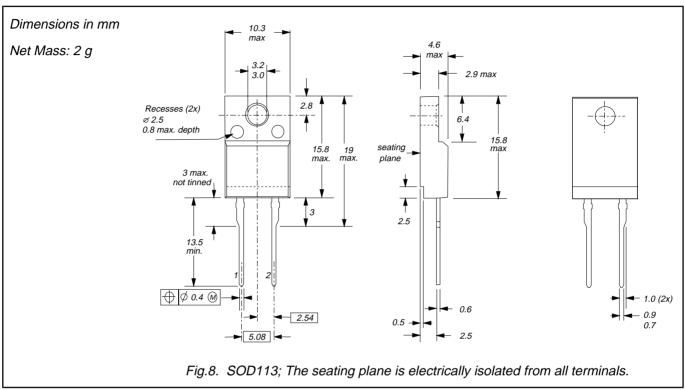
## **MECHANICAL DATA**



- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

# PBYR1645F, PBYR1645X

## **MECHANICAL DATA**



## **Notes**

- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

# Rectifier diodes Schottky barrier

PBYR1645F, PBYR1645X

#### **DEFINITIONS**

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

#### © Philips Electronics N.V. 1998

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.